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ELIS-1024

Enhanced High Performance Linear CMOS Image Sensor

The ELIS-1024 image sensor is a high performance, very low noise linear image sensor designed for a wide variety of applications including:



P/N: ELIS-1024A-LG
16-pin LCC package

- **Spectroscopy**
- **Bar Code Reading**
- **Edge Detection**
- **Contact Scanning**
- **Optical Character Recognition**
- **Encoding**
- **Position Detection**
- **And more.....**

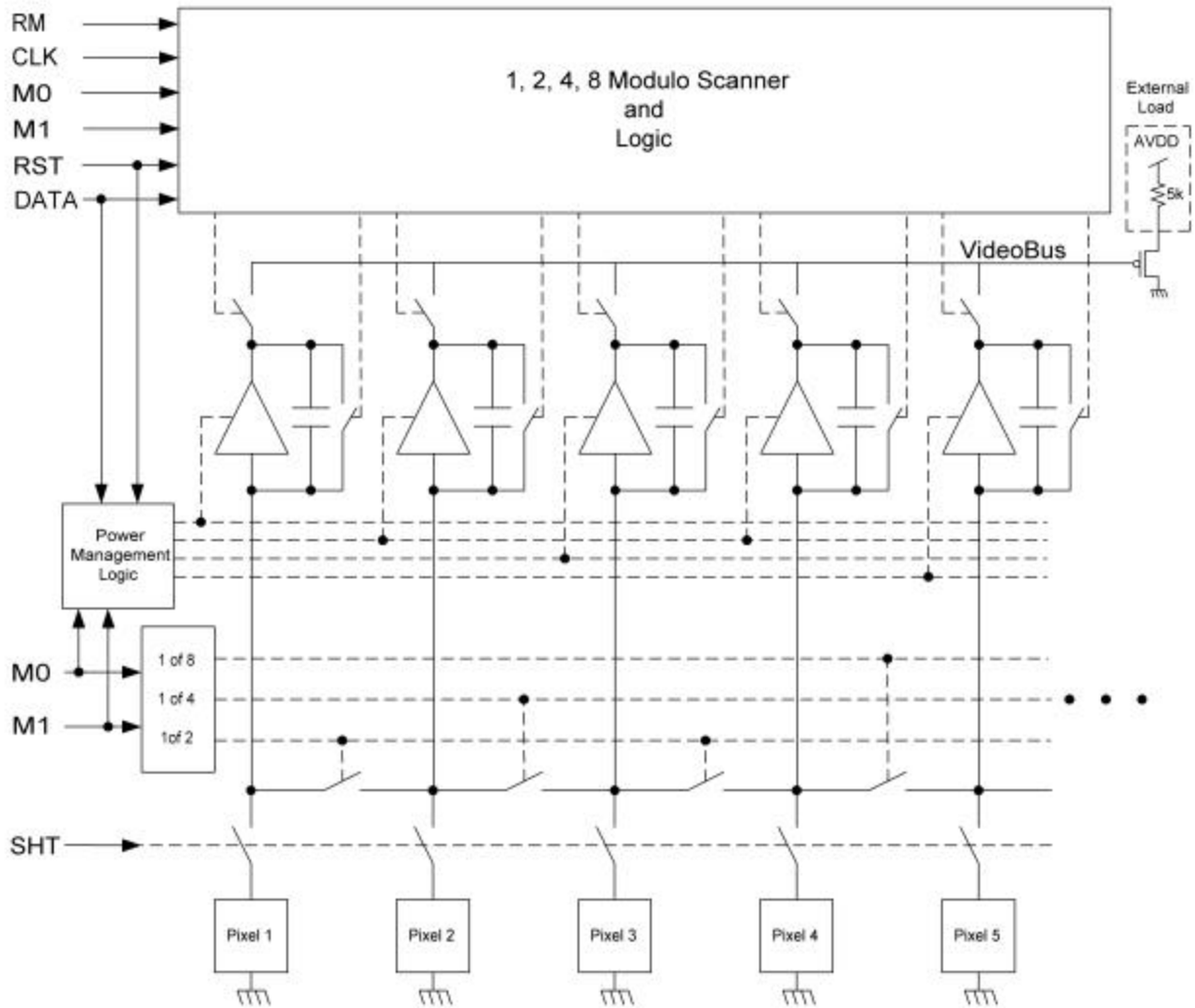
Description

The ELIS-1024 Linear Image Sensor consists of an array of high performance, low dark current photo-diode pixels. The sensor features sample and hold capability, selectable resolution and advanced power management. The device can operate at voltages as low as 2.8V making it ideal for portable applications. A key feature over traditional CCD technology is that the device can be read and reread Non-Destructively, allowing the user to maximize signal to noise and dynamic range. Internal logic automatically reduces power consumption when lower resolution settings are selected. A low power standby mode is also available to reduce system power consumption when the imager is not in use.

Key Features

- Low Cost
- Single Voltage Operation, Wide Operating Range
- Selectable Resolutions of 1024, 512, 256 and 128 pixels
- Very Low Power via Intelligent Power Management and Low-Power Standby Mode
- Sample and Hold
- Full Frame Shutter and Dynamic Pixel Reset (DPR) Modes
- High Sensitivity
- High Signal to Noise, very low dark current
- Non-Destructive Read mode, extremely low noise capable via signal averaging
- Completely Integrated Timing and Control

FUNCTIONAL BLOCK DIAGAM



PIN DESCRIPTION – 16-Pin LCC Package

1, 12	AGND		Analog Ground
2, 11	AVDD		Analog Power
3	DATA	Input	Start Readout
4	RST	Input	Reset
5	M0	Input	Bin Select Bit 0
6	M1	Input	Bin Select Bit 1
7	SHT	Input	Shutter
8, 9	N/C		No Connection
10	VOOUT	Output	Analog Video Output (requires external pull-up resistor)
13	RM	Input	Reset Mode: RM = 0 for frame mode, RM = 1 for DPR mode
14	DVDD		Digital Power
15	DGND		Digital Ground
16	CLK	Input	Master Clock (@ pixel rate)

Electro-Optical Characteristics

Specs given at 24°C, 5.0V, 1MHz clock with 50% duty cycle and a 3200K light source unless otherwise noted.

Parameter	Min	Typical	Max	Units
Supply Voltage	2.80	5.0	5.5	V
Supply Current (see Note 1): Res = 1024 Res = 512 Res = 256 Res = 128		20.0 11.0 6.5 4.0		mA
Standby Current		25		μA
Input High Logic Level	V _{DD} -0.6V			V
Input Low Logic Level			0.6	V
Clock Frequency/Pixel Read Rate (see Note 3)	1.0	1000	30,000	kHz
External Pull-up Load		5000		Ω
Output Voltage at Saturation (see Note 4)		4.8		V
Output Voltage at Dark		2.1		V
Conversion Gain: Res = 1024 Res = 512 Res = 256 Res = 128		0.83 0.98 1.18 1.51		μV/e ⁻
Full Well:(note 7) Res = 1024 Res = 512 Res = 256 Res = 128		3.26 2.77 2.28 1.79		Me ⁻
Dynamic Range (note 7)		71		dB
Pixel Non-Uniformity Dark		±0.5		%Sat
Linearity (see Note 2)		0.8		%
Output due to Dark Current (note 6)		8		mV/s
Fill Factor		100		%Area
Absolute QE at peak (675nm)		60		%
Read Noise (see Note 5)		0.8		mVrms

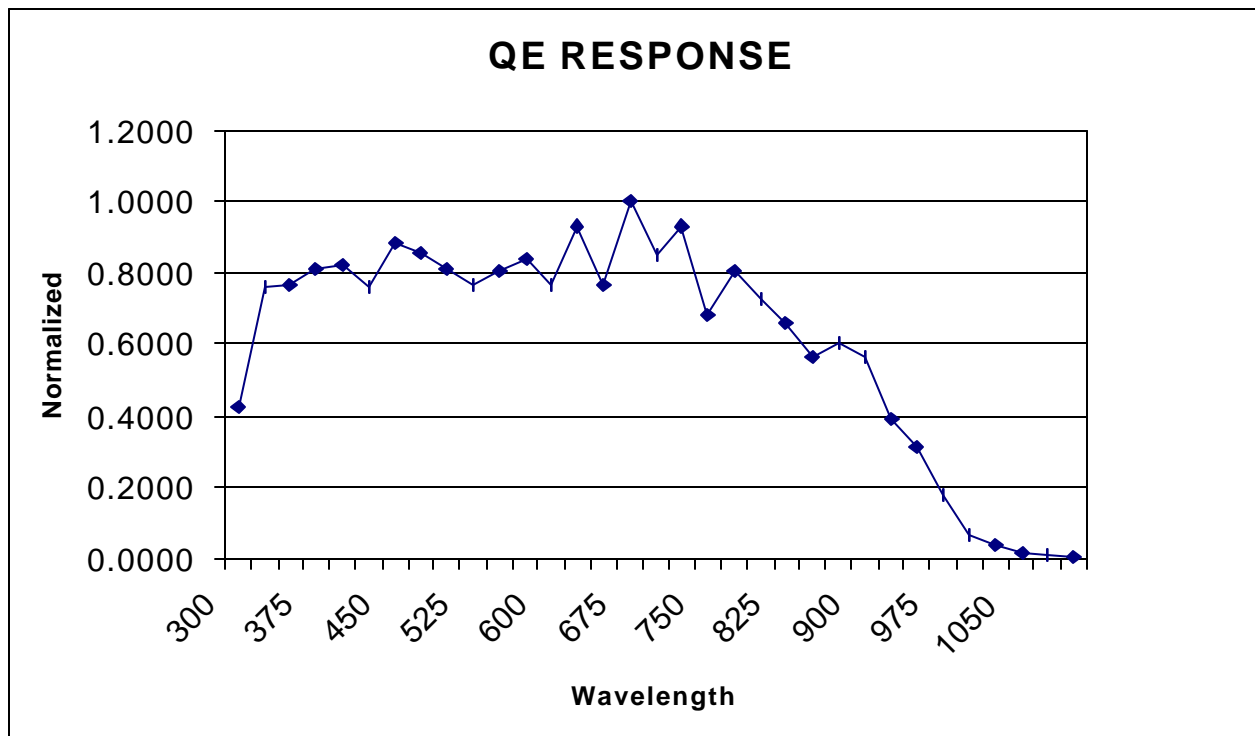
- Notes
1. Includes 5k load resistor and measured at dark. Increased speed increases power consumption.
 2. Pixel average from 5% - 75% saturation.
 3. Specs given at pixel read rates of 1 MHz at 24°C. At greater read rates MTF and Dynamic Range begin to degrade. Higher speeds may not be possible at lower supply voltages.
 4. At supply voltages less than saturation voltage, Vout is clipped by supply, no load applied.
 5. Temporal rms noise @ 1 MHz pixel rate and 500kHz video bandwidth filter applied, values are typical and may vary. Higher Dynamic Range is possible with lower pixel rates and bandwidths.
 6. Output due to dark current changes approximately 1.4mV/°C.
 7. Values are internally limited.

Absolute maximum ratings, $T_A = 25^\circ\text{C}$ unless otherwise noted, see Note 1, below. †

Supply voltage range, V_{DD}	0 V to 6.0 V
Digital input current range, I_I	-16 mA to 16 mA
Operating case temperature range, T_C (see Note 2)	0°C to 70°C
Operating free-air temperature range, T_A	0°C to 50°C
Storage temperature range	-20°C to 85°C
Humidity range, RH	0-100%, non-condensing
Lead temperature 1.5 mm (0.06 inch) from case for 10 seconds	235°C

† Exceeding the ranges specified under “absolute maximum ratings” can damage the device. The values given are for stress ratings only. Operation of the device at conditions other than those indicated under “recommended operating conditions” is not implied. Exposing the device to absolute maximum rated conditions for extended periods may affect device reliability and performance.

- NOTES: 1. Voltage values are with respect to the device GND terminal.
2. Case temperature is defined as the surface temperature of the package measured directly over the integrated circuit.



Note: Data below 350nm not measured, but device is sensitive to 200 nm. The QE peaks at 675nm. Shown for un-filtered and un-covered device.

Resolution Selection

By setting the M0 and M1 inputs as indicated in Table 1, several effective resolutions can be realized. The effective imager length is 7.987mm regardless of the selected resolution. Internally, the device has 1024 pixels. As the resolution decreases the effective pixel area increases as in Table 1. When the resolution is set to 512, the photodiodes of pixels 1 and 2 are averaged and output as a single value, pixels 3 and 4 are averaged and output as a single value, and so on. If set to 256 resolution, then pixels 1 through 4 are averaged and output as a single value, 5 through 8 are averaged and output as a single value, and so on. The internal control logic determines the resolution and always outputs a valid pixel per clock cycle. For example, if the imager is selected for 256-pixel resolution, then only 256 clock cycles are needed to read out the imager once DATA is set. Thus, for lower resolutions higher frame rates are possible as indicated in Table 1.

Table 1: Resolution Select.

M1	M0	Resolution	Effective Pixel Size	Frame Rate @ 1MHz Clock (frames/s)
0	0	1024	7.8 x 125 μ m	976
0	1	512	15.6 x 125 μ m	1953
1	0	256	31.2 x 125 μ m	3906
1	1	128	64.4 x 125 μ m	7812

Power Management and Standby Mode

This device incorporates internally controlled power management features and an externally controlled low-power Standby Mode. When resolutions lower than 1024-pixels are selected, internal logic disables the unused amplifiers reducing the power consumption. Utilizing the existing external signals RST and DATA a low-power Standby Mode is possible. When RST and DATA are simultaneously held high the entire imager is put into Standby Mode. In this mode all internal amplifiers are disabled, the internal clocks are stopped and the output amplifier is also disabled. The clock can be held low or high or remain running while the imager is held in standby.

Frame Mode Timing (RM = 0)

In Frame Mode three signals are required for operation not including resolution selection and CLK. These being reset (RST), shutter (SHT) and start data readout (DATA). Both RST and SHT are asynchronous to the system clock, which allows unlimited reset and integration timing resolution.

Standard Timing

The timing relations for Standard Timing are shown in Figure 1 and detailed descriptions are given below. In the VIDEO waveform the 'X Clock Cycles' is determined by the resolution selected. The clock should be 50% duty cycle.

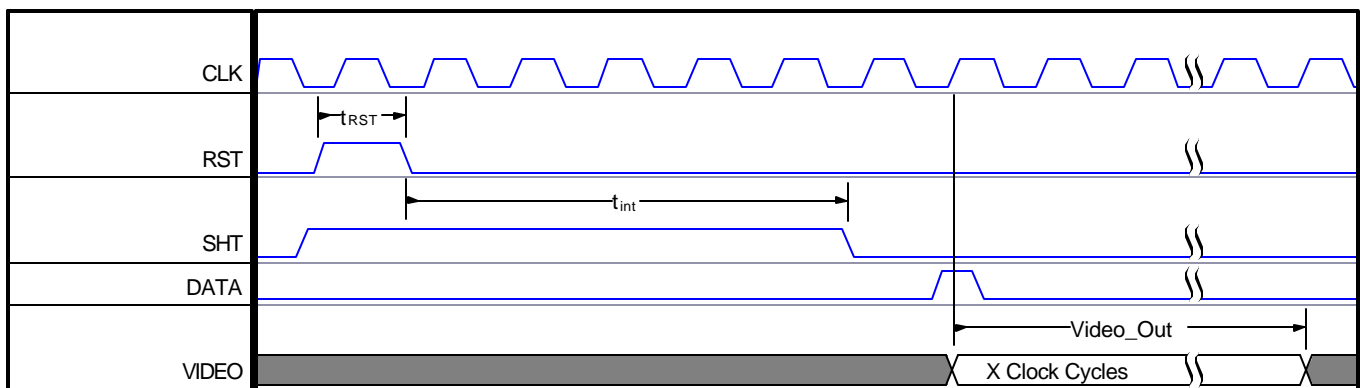


Figure 1: Start of Frame Timing Diagram.

Device Reset:

The pixels are simultaneously reset while the RST and SHT inputs are both held high for at least 200ns, as indicated by t_{RST} . The imager can be held in reset indefinitely by keeping both inputs high. When RST is high the internal clocks to the shift register are disabled and the shift register is held in reset. Once RST goes low the shift register comes out of reset and the clocks begin running.

Integration:

Once RST goes low (while SHT is high), the pixels begin to integrate. Integration continues until SHT goes low as indicated by t_{int} .

Readout:

Readout will begin on the first rising edge of CLK after the DATA input is set high. DATA must be brought low prior to the next rising edge of CLK, otherwise pixel 1 is again output along with pixel 2. See Figure 2 for details. The RST pulse always resets the internal shift register, thus the next pixel to be readout after the first rising edge of CLK when DATA is asserted is the first pixel. The timing details of the DATA pulse are shown below, $t_D = 10\text{ns}$.

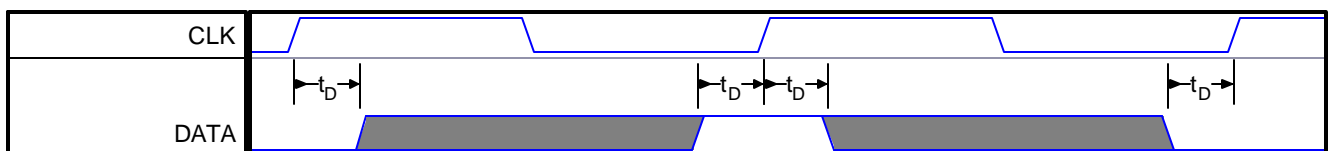


Figure 2: Detailed DATA Pulse Timing Diagram.

Non-Destructive Readout (NDRO)

NDRO mode is similar to the standard mode of operation except that the pixels are readout multiple times for a single integration time. The required signal timings are shown in Figure 3.

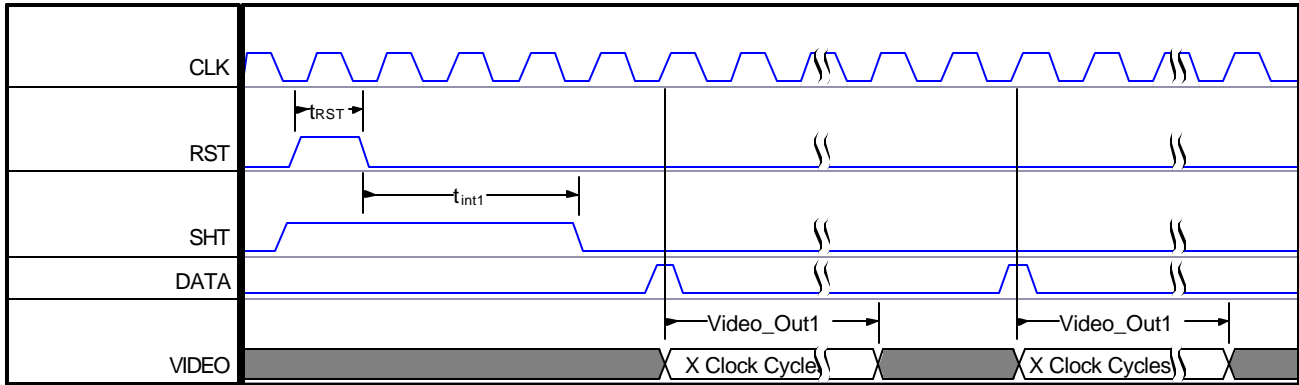


Figure 3: Non-Destructive Readout Timing Diagram.

Dynamic Pixel Reset (DPR) Mode Timing (RM = 1)

In DPR mode the pixels are reset by internal signals, which eliminates the need for using the external reset pin. When operating in DPR mode RST must be held low otherwise the internal logic will be held in reset. However, RST does NOT reset the pixels in DPR mode. Since the pixels are continuously integrating (except the one clock cycle they are being reset) the SHT pin should always be held high. The first frame readout will be invalid because the pixels will have been integrating for an unknown period of time. Valid video will be generated during the second frame. The required signal timings are illustrated in Figure 4.

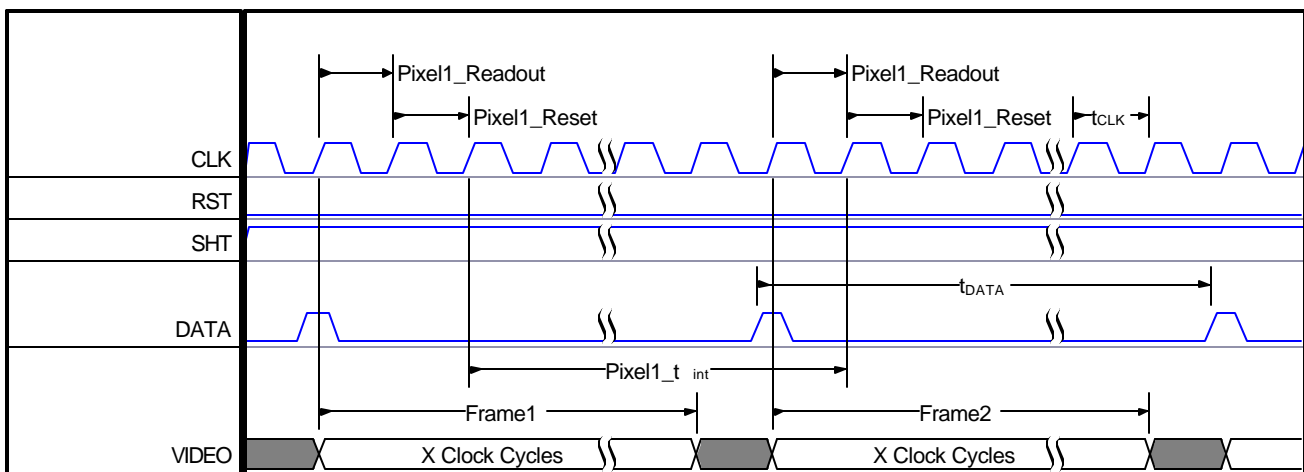


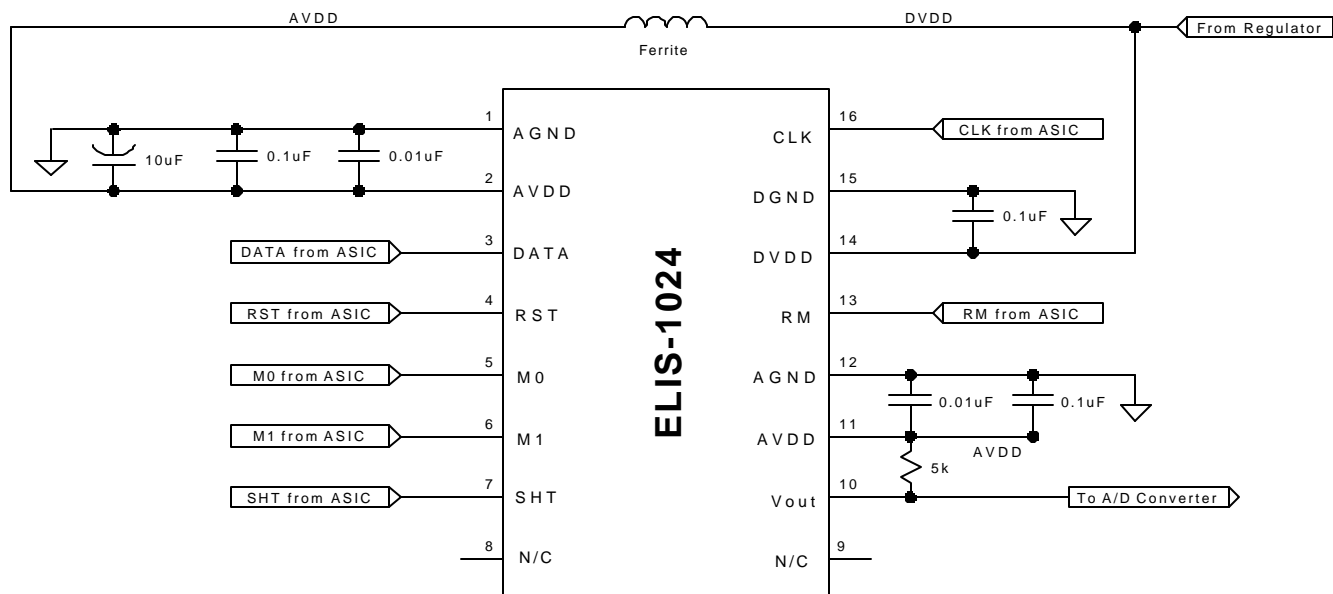
Figure 4: DPR Mode Timing Diagram.

Pixel 1 was used as an example to show the key timing situations. During the first clock cycle after DATA is high pixel 1 is readout. Then while pixel 2 is being readout during the second clock cycle

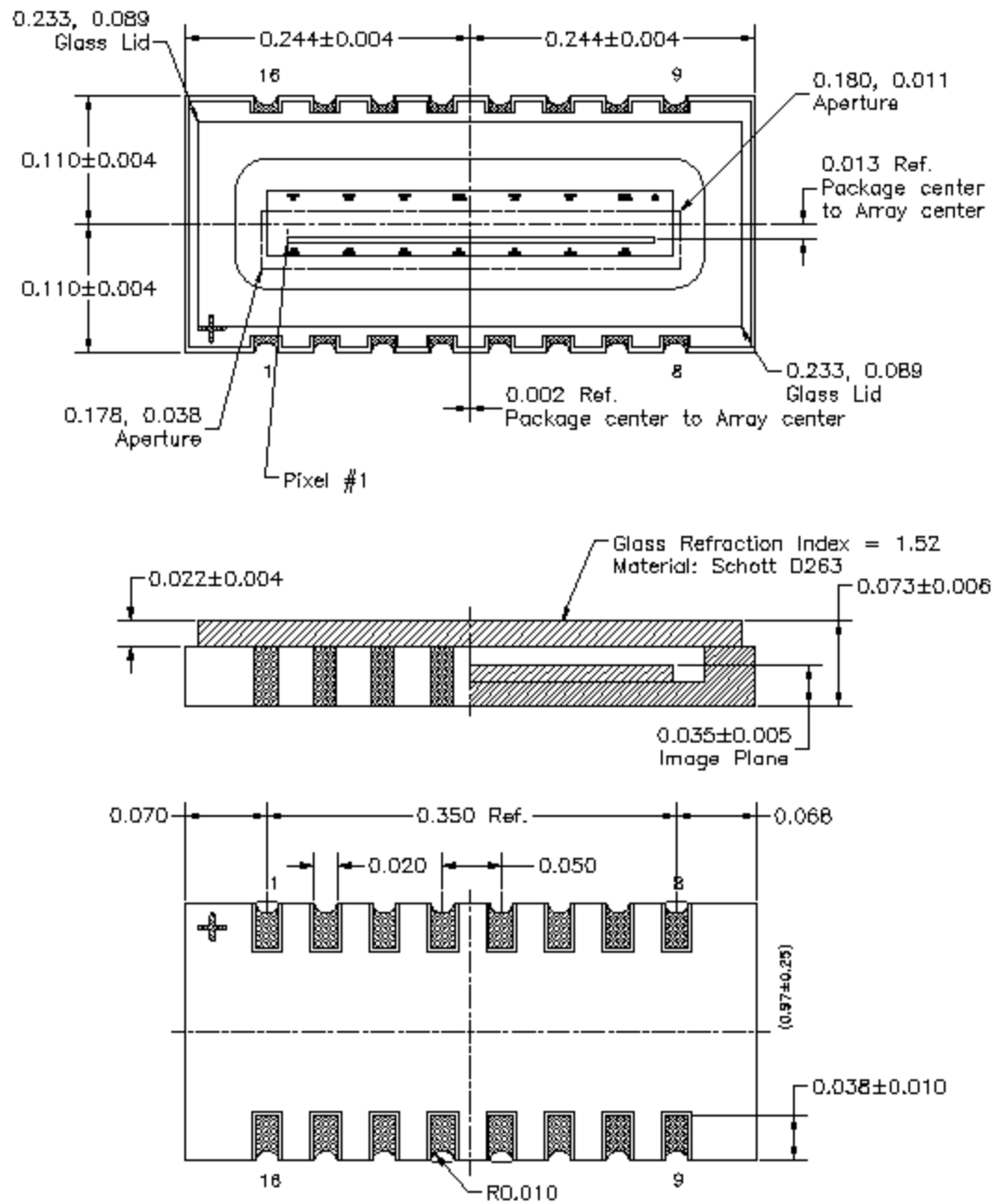
pixel one is being reset. The integration time for pixel 1 then becomes the time between the rising edge of the third clock pulse of Frame 1 to the rising edge of the second clock of Frame 2. In general the integration time is the period of DATA less one clock cycle ($t_{int} = t_{DATA} - t_{CLK}$). In reality the integration time ends when the signal is sampled by the external circuitry.

A one-clock cycle delay between the end of Frame 1 and start of Frame 2 is shown in Figure 4. This delay can be as low as zero clock cycles and as high as desired. There is no restriction to the delay between frames but at very long integration times dark current may become an issue.

Typical Application Circuit



LCC Package Mechanical Information



ORDERING INFORMATION

These devices are offered in a Leadless Chip Carrier package.

ELIS-1024A-LG Leadless Chip Carrier (LCC)

Contact Silicon Video, Inc. or your local authorized representative for availability.

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